

MIC38C42/3/4/5

BiCMOS Current-Mode PWM Controllers

General Description

The MIC38C4x are fixed frequency, high performance, current-mode PWM controllers. Micrel's BiCMOS devices are pin compatible with 384x bipolar devices but feature several improvements.

Undervoltage lockout circuitry allows the '42 and '44 versions to start up at 14.5V and operate down to 9V, and the '43 and '45 versions start at 8.4V with operation down to 7.6V. All versions operate up to 20V.

When compared to bipolar 384x devices operating from a 15V supply, start-up current has been reduced to 50µA typical and operating current has been reduced to 4.0 mA typical. Decreased output rise and fall times drive larger MOSFETs, and rail-to-rail output capability increases efficiency, especially at lower supply voltages. The MIC38C4x also features a trimmed oscillator discharge current and bandgap reference.

MIC38C4x denotes 8-pin plastic DIP, SOIC, and MM8[™] packages. MIC38C4x-1 denotes 14-pin plastic DIP and SOIC packages. 8-pin devices feature small size, while 14-pin devices separate the analog and power connections for improved performance and power dissipation.

Features

- Fast 40ns output rise and 30ns output fall times
- -40°C to +85°C temperature range meets UC284x specifications
- High-performance, low-power BiCMOS Process
- Ultralow start-up current (50µA typical)
- Low operating current (4mA typical)
- CMOS outputs with rail-to-rail swing
- ≥ 500kHz current-mode operation
- Trimmed 5V bandgap reference
- Pin-for-pin compatible with UC3842/3843/3844/3845(A)
- Trimmed oscillator discharge current
- UVLO with hysteresis
- Low cross-conduction currents

Applications

- Current-mode, off-line, switched-mode power supplies
- Current-mode, dc-to-dc converters.
- Step-down "buck" regulators
- Step-up "boost" regulators
- Flyback, isolated regulators
- Forward converters
- Synchronous FET converters

For fast rise and fall times and higher output drive, refer to the MIC38HC4x.



Functional Diagram

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Micrel, Inc. • 1849 Fortune Drive • San Jose, CA 95131 • USA • tel + 1 (408) 944-0800 • fax + 1 (408) 944-0970 • http://www.micrel.com

Part Number	Temperature Range	Package
MIC38C42BN	–40°C to +85°C	8-pin Plastic DIP
MIC38C43BN	–40°C to +85°C	8-pin Plastic DIP
MIC38C44BN	–40°C to +85°C	8-pin Plastic DIP
MIC38C45BN	–40°C to +85°C	8-pin Plastic DIP
MIC38C42-1BN	–40°C to +85°C	14-pin Plastic DIP
MIC38C43-1BN	–40°C to +85°C	14-pin Plastic DIP
MIC38C44-1BN	–40°C to +85°C	14-pin Plastic DIP
MIC38C45-1BN	–40°C to +85°C	14-pin Plastic DIP
MIC38C42BM	–40°C to +85°C	8-pin SOIC
MIC38C43BM	–40°C to +85°C	8-pin SOIC
MIC38C44BM	–40°C to +85°C	8-pin SOIC
MIC38C45BM	–40°C to +85°C	8-pin SOIC
MIC38C42BMM	–40°C to +85°C	8-pin MM8™
MIC38C43BMM	–40°C to +85°C	8-pin MM8™
MIC38C44BMM	–40°C to +85°C	8-pin MM8™
MIC38C45BMM	–40°C to +85°C	8-pin MM8™
MIC38C42-1BM	–40°C to +85°C	14-pin SOIC
MIC38C43-1BM	–40°C to +85°C	14-pin SOIC
MIC38C44-1BM	–40°C to +85°C	14-pin SOIC
MIC38C45-1BM	–40°C to +85°C	14-pin SOIC

Ordering Information

Refer to the Part Number Cross Reference for a listings of Micrel devices equivalent to UC284x and UC384x devices.

Selection Guide

	UVLO Thresholds	
Duty Cycle	Startup 8.4V Minimum Operating 7.6V	Startup 14.5V Minimum Operating 9V
0% to 96%	MIC38C43	MIC38C42
0% to 50%	MIC38C45	MIC38C44

Pin Configuration



8-Pin DIP (N) 8-Lead SOIC (M) 8-Lead MM8™ (MM)







14-Pin DIP (-1BN) 14-Lead SOIC (-1BM)

Absolute Maximum Ratings

Zener Current (V _{DD})					
Operation at ≥18V may require					
special precautions (Note 6).					
Supply Voltage (V _{DD}), Note 6	20V				
Switch Supply Voltage (V _D)	20V				
Current Sense Voltage (VISNS)0.3V to	5.5V				

Current Sense Voltage (V _{ISNS})	–0.3V to 5.5V
Feedback Voltage (V _{FB})	–0.3V to 5.5V
Output Current, 38C42/3/4/5 (I _{OUT})	0.5A
Storage Temperature (T _A)	65°C to +150°C

Operating Ratings

Junction Temperature (T _J)	150°C
Package Thermal Resistance	
8-Pin Plastic DIP (θ_{JA})	125°C/W
8-Pin MM8™ (θ _{.IA})	
8-Pin SOIC (θ _{.IA})	170°C/W
14-Pin Plastic DIP (θ _{JA})	
14-Pin SOIC (θ_{JA})	

Electrical Characteristics

 V_{DD} = 15V, Note 4; R_{T} = 11.0k; C_{T} = 3.3nF; –40°C \leq T_{A} \leq 85°C; unless noted

Parameter	Test Conditions	Min	Тур	Max	Units
Reference Section		•	•	1	•
Output Voltage	$T_A = 25^{\circ}C, I_O = 1mA$	4.90	5.00	5.10	V
Line Regulation	$12V \le V_{DD} \le 18V$, $I_O = 5\mu A$, Note 6		2	20	mV
Load Regulation	$1 \le I_O \le 20 \text{mA}$		1	25	mV
Temp. Stability	Note 1		0.2		mV/°C
Total Output Variation	Line, Load, Temp., Note 1	4.82		5.18	V
Output Noise Voltage	$10Hz \le f \le 10kHz$, $T_A = 25^{\circ}C$, Note 1		50		μV
Long Term Stability	T _A = 125°C, 1000 hrs., Note 1		5	25	mV
Output Short Circuit		-30	-80	-180	mA
Oscillator Section		·			
Initial Accuracy	T _A = 25°C, Note 5	49	52	55	kHz
Voltage Stability	12 ≤ V _{DD} ≤ 18V, Note 6		0.2	1.0	%
Temp. Stability	$T_{MIN} \le T_A \le T_{MAX}$, Note 1		0.04		%/°C
Clock Ramp	$T_A = 25^{\circ}C, V_{RT/CT} = 2V$	7.7	8.4	9.0	mA
Reset Current	$T_A = T_{MIN}$ to T_{MAX}	7.2	8.4	9.5	mA
Amplitude	V _{RT/CT} peak to peak		1.9		Vp-p
Error Amp Section					
Input Voltage	$V_{COMP} = 2.5V$	2.42	2.50	2.58	V
Input Bias Current	V _{FB} = 5.0V		-0.1	-2	μA
A _{VOL}	$2 \le V_0 \le 4V$	65	90		dB
Unity Gain Bandwidth	Note 1	0.7	1.0		MHz
PSRR	$12 \le V_{DD} \le 18V$	60			dB
Output Sink Current	V _{FB} = 2.7V, V _{COMP} = 1.1V	2	14		mA
Output Source Current	V _{FB} = 2.3V, V _{COMP} = 5V	-0.5	-1		mA
V _{OUT} High	V_{FB} = 2.3V, R_L = 15k to ground	5	6.8		V
V _{OUT} Low	V_{FB} = 2.7V, R_L = 15k to V_{REF}		0.1	1.1	V

Parameter	Test Conditions	Min	Тур	Max	Units
Current Sense	-	·		•	
Gain	Notes 2, 3	2.85	3.0	3.15	V/V
MaximumThreshold	V _{COMP} = 5V, Note 2	0.9	1	1.1	V
PSRR	$12 \le V_{DD} \le 18V$, Note 2		70		dB
Input Bias Current			-0.1	-2	μA
Delay to Output			120	250	ns
Output	-	•	-		<u></u>
R _{DS(ON)} High R _{DS(ON)} Low	I _{SOURCE} = 200mA I _{SINK} = 200mA		20 11		Ω Ω
Rise Time	$T_{A} = 25^{\circ}C, C_{L} = 1nF$		40	80	ns
Fall Time	$T_{A} = 25^{\circ}C, C_{L} = 1nF$		30	60	ns
Undervoltage Lockout		-			
Start Threshold	MIC38C42/4	13.5	14.5	15.5	V
	MIC38C43/5	7.8	8.4	9.0	V
Minimum Operating Voltage	MIC38C42/4	8	9	10	V
	MIC38C43/5	7.0	7.6	8.2	V
Pulse Width Modulator					
Maximum Duty Cycle	MIC38C42/3	94	96		%
	MIC38C44/5	46	50		%
Minimum Duty Cycle				0	%
Total Standby Current		•	-	•	•
Start-Up Current	$V_{DD} = 13V$ for MIC38C42/44 $V_{DD} = 7.5V$ for MIC38C43/45		50	200	μA
Operating Supply Current	$V_{FB} = V_{ISNS} = 0V$		4.0	6.0	mA
Zener Voltage (V _{DD})	I _{DD} = 25mA, Note 6	30	37		V

Note 1: These parameters, although guaranteed, are not 100% tested in production. **Note 2:** Parameter measured at trip point of latch with $V_{EA} = 0$.

Note 3: Gain defined as:

$$A = \frac{\Delta V_{PIN1}}{V_{TH} (I_{SNS})}; 0 \le V_{TH} (I_{SNS}) \le 0.8V$$

Note 4: Adjust $V_{_{DD}}$ above the start threshold before setting at 15V.

Note 5: Output frequency equals oscillator frequency for the MIC38C42 and MIC38C43. Output frequency for the MIC38C44, and MIC38C45 equals one half the oscillator frequency.

Note 6: On 8-pin version, 20V is maximum input on pin 7, as this is also the supply pin for the output stage. On 14-pin version, 40V is maximum for pin 12 and 20V maximum for pin 11.

 R_T RESISTANCE (k Ω)

Typical Characteristics



25°C

6

8

-50°Ċ

2

0

4

ERROR AMPLIFIER OUTPUT (V)









Application Information

Familiarity with 384x converter designs is assumed.

The MIC38C4x has been designed to be compatible with 384xA series controllers.

MIC38C4x Advantages

Start-up Current

Start-up current has been reduced to an ultra-low $50\mu A$ (typical) permitting higher-valued, lower-wattage, start-up resistors (powers controller during power supply start-up). The reduced resistor wattage reduces cost and printed circuit space.

Operating Current

Operating current has been reduced to 4mA compared to 11mA for a typical bipolar controller. The controller runs cooler and the V_{DD} hold-up capacitance required during start-up may be reduced.

Output Driver

Complementary internal P- and N-channel MOSFETs produce rail-to-rail output voltages for better performance driving external power MOSFETs. The driver transistor's low onresistance and high peak current capability can drive gate capacitances of greater than 1000pF. The value of output capacitance which can be driven is determined only by the rise/fall time requirements. Within the restrictions of output capacity and controller power dissipation, maximum switching frequency can approach 500kHz.

Design Precautions

When operating near 20V, circuit transients can easily exceed the 20V absolute maximum rating, permanently damaging the controller's CMOS construction. To reduce transients, use a 0.1μ F low-ESR capacitor to next to the controller's

supply V_{DD} (or V_{D} for '-1' versions) and ground connections. Film type capacitors, such as Wima MKS2, are recommended.

When designing high-frequency converters, avoid capacitive and inductive coupling of the switching waveform into highimpedance circuitry such as the error amplifier, oscillator, and current sense amplifier. Avoid long printed-circuit traces and component leads. Locate oscillator and compensation circuitry near the IC. Use high frequency decoupling capacitors on V_{REF}, and if necessary, on V_{DD}. Return high *di/dt* currents directly to their source and use large area ground planes.

Buck Converter

Refer to figure 1. When at least 26V is applied to the input, C5 is charged through R2 until the voltage V_{DD} is greater than 14.5V (the undervoltage lockout value of the MIC38C42). Output switching begins when Q1 is turned on by the gate drive transformer T1, charging the output filter capacitor C3 through L1. D5 supplies a regulated +12V to V_{DD} once the circuit is running.

Current sense transformer CT1 provides current feedback to ISNS for current-mode operation and cycle-by-cycle current limiting. This is more efficient than a high-power sense resistor and provides the required ground-referenced level shift.

When Q1 turns off, current flow continues from ground through D1 and L1 until Q1 is turned on again.

The 100V Schottky diode D1 reduces the forward voltage drop in the main current path, resulting in higher efficiency than could be accomplished using an ultra-fast-recovery diode. R1 and C2 suppress parasitic oscillations from D1.

Using a high-value inductance for L1 and a low-ESR capacitor for C3 permits small capacitance with minimum output



Figure 1. 500kHz, 25W, Buck Converter

 $V_{IN} = 26V$ to 80V, $I_{O} = 2A$ Line Regulation $V_{IN} = 48V, I_{O} = 0.2A$ to 2A Load Regulation V_{IN} = 48V, I_O = 2A Efficiency Output Ripple V_{IN} = 48V, I_O = 2A (20MHz BW)

Conditions

ripple. This inductance value also improves circuit efficiency

Magnetic components are carefully chosen for minimal loss

at 500kHz. CT1 and T1 are wound on Magnetics, Inc. P-type material toroids. L1 is wound on a Siemens N49 EFD core.

Symbol	Custom Coil ¹	ETS ²
CT1	4923	ETS 92420
T1	4924	ETS 92419
L1	4925	ETS 92421

1. Custom Coils, Alcester, SD tel: (605) 934-2460

MIC5022

VDD

FLT

ΕN

IN

СТ

GND

NC O

NC O-

NC O

GATEH

GATEL

SH+

SH-

SL+

SL

VB

0.1uF

2. Energy Transformation Systems, Inc. tel: (415) 324-4949.

Synchronous Buck Converter

10k€

47k

3.3k **≨**10k

≷6.8k

by reducing the flux swing in L1.

Refer to figure 2. This MIC38C43 synchronous buck converter uses an MIC5022 half-bridge driver to alternately drive the PWM switch MOSFET (driven by GATEH, or high-side output) and a MOSFET which functions as a synchronous rectifier (driven by the GATEL, or low-side output).

The low-side MOSFET turns on when the high-side MOSFET is off, allowing current to return from ground. Current flows through the low-side MOSFET in the source to drain direction.

0.15µF

4.7nF

300k

4.3k

MIC38C43

VREF

VDD

VOUT

GND

COMP

ISNS

RT/CT

FB

The on-state voltage drop of the low-side MOSFET is lower than the forward voltage drop of an equivalent Schottky rectifier. This lower voltage drop results in higher efficiency.

A sense resistor $(5m\Omega)$ is connected to the driver's high-side current sense inputs to provide overcurrent protection. Refer to the MIC5020, MIC5021, and MIC5022 data sheets for more information.

SMP60N06-14

35µH

 $5m\Omega$

V_{OUT}

5V, 8A

-0

1000µF Low ESR

|+



Results

0.5%

0.6%

90%

100mV

+12V

0.1µF

0 1uF

MKS2

*Locate near the MIC38C43 supply pins.

470uF

25V

T

MIC38C42/3/4/5

Figure 2. 100kHz, Synchronous Buck Converter

Test

Package Information



0.026 (0.65)

MAX

ΠΠ

DIMENSIONS: INCHES (MM)



14-Pin SOP (M)

MICREL INC. 1849 FORTUNE DRIVE SAN JOSE, CA 95131 USA

TEL + 1 (408) 944-0800 FAX + 1 (408) 944-0970 WEB http://www.micrel.com

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